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Thick Film Chip Resistors

Type: **ERJ XG, 1G, 2G, 3G, 6G, 8G, 14, 12, 12Z, 1T**

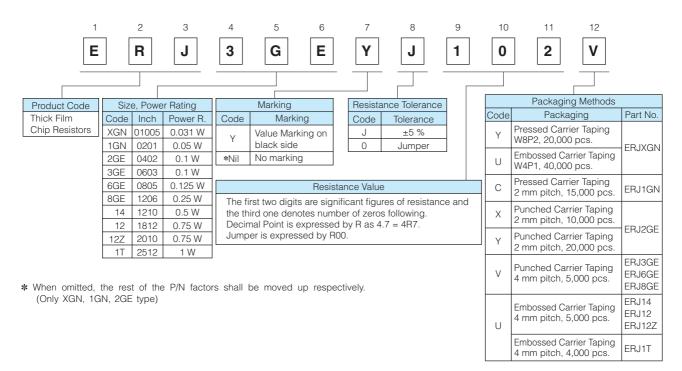


Features

- Small size and lightweight
- High reliability
 Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines
 Taping packaging available
- Suitable for both reflow and flow soldering
- Reference Standards IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B
- AEC-Q200 qualified (Exemption ERJXG)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions,
 Please see Data Files

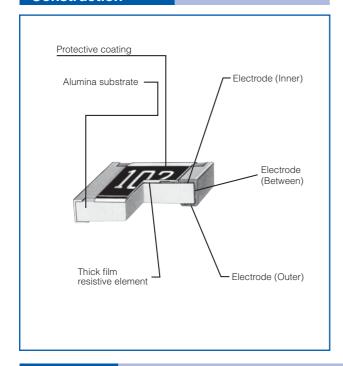
Explanation of Part Numbers

● ERJXGN, 1GN, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T Type, ±5 %

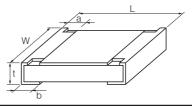


Thick Film Chip Resistors

Construction



Dimensions in mm (not to scale)



Part No.		Mass (Weight)					
(inch size)	L	W	а	b	t	(g/1000 pcs.)	
ERJXG (01005)	0.40 ^{±0.02}	0.20 ^{±0.02}	0.10 ^{±0.03}	0.10 ^{±0.03}	0.13 ^{±0.02}	0.04	
ERJ1G (0201)	0.60 ^{±0.03}	0.30 ^{±0.03}	0.10 ^{±0.05}	0.15 ^{±0.05}	0.23 ^{±0.03}	0.15	
ERJ2G (0402)	1.00 ^{±0.05}	0.50 ^{±0.05}	0.20 ^{±0.10}	0.25 ^{±0.05}	0.35 ^{±0.05}	0.8	
ERJ3G (0603)	1.60 ^{±0.15}	0.80+0.15	0.30 ^{±0.20}	0.30 ^{±0.15}	0.45 ^{±0.10}	2	
ERJ6G (0805)	2.00 ^{±0.20}	1.25 ^{±0.10}	0.40 ^{±0.20}	0.40 ^{±0.20}	0.60 ^{±0.10}	4	
ERJ8G (1206)	3.20+0.05	1.60+0.05	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	10	
ERJ14 (1210)	3.20 ^{±0.20}	2.50 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	16	
ERJ12 (1812)	4.50 ^{±0.20}	3.20 ^{±0.20}	0.50 ^{±0.20}	0.50 ^{±0.20}	0.60 ^{±0.10}	27	
ERJ12Z (2010)	5.00 ^{±0.20}	2.50 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	27	
ERJ1T (2512)	6.40 ^{±0.20}	3.20 ^{±0.20}	0.65 ^{±0.20}	0.60 ^{±0.20}	0.60 ^{±0.10}	45	

Ratings

[For Resistor]

[For Hoolster]							
Part No. (inch size)	Power Rating at 70 °C (W)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /°C)	Category Temperature Range (°C)
ERJXG (01005)	0.031	15	30	±5	4.7 to 1 M (E24)	$<10 \Omega$: -100 to $+600$ 10 Ω to 100Ω : ± 300 100 Ω <: ± 200	-55 to +125
ERJ1G (0201)	0.05	25	50	±5	1 to 10 M (E24)	<10 Ω: -100 to +600	-55 to +125
ERJ2G (0402)	0.1	50	100	±5	1 to 10 M (E24)		-55 to +155
ERJ3G (0603)	0.1	75	150	±5	1 to 10 M (E24)		-55 to +155
ERJ6G (0805)	0.125	150	200	±5	1 to 10 M (E24)		-55 to +155
ERJ8G (1206)	0.25	200	400	±5	1 to 10 M (E24)	10 Ω to 1 M Ω : ±200	-55 to +155
ERJ14 (1210)	0.5	200	400	±5	1 to 10 M (E24)		-55 to +155
ERJ12 (1812)	0.75	200	500	±5	1 to 10 M (E24)		-55 to +155
ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M (E24)	1 M Ω <: -400 to +150	-55 to +155
ERJ1T (2512)	1	200	500	±5	1 to 1 M (E24)		-55 to +155

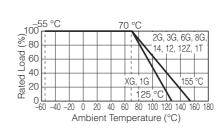
⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

[For Jumper]

[i or bumper]							
Part No.	Rated Current	Maximum Overload Current					
(inch size)	(A)	(A)					
ERJXG (01005)	0.5	1					
ERJ1G (0201)	0.5	l l					
ERJ2G (0402)	1	2					
ERJ3G (0603)	'						
ERJ6G (0805)							
ERJ8G (1206)							
ERJ14 (1210)	2	1					
ERJ12 (1812)		4					
ERJ12Z (2010)							
ERJ1T (2512)							

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



⁽²⁾ Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5 (Only ERJ2G=2.0) × Power Rating or max. Overload Voltage listed above whichever less.